



B.Tech I Semester Regular Examinations, March/April 2023

Basic Electrical and Electronics Engineering
(CE)

Maximum Marks: 60

Date:12.04.2023 Duration: 3 hours

- Note:
1. This question paper contains two parts A and B.
 2. Part A is compulsory which carries 10 marks. Answer all questions in Part A.
 3. Part B consists of 5 Units. Answer any one full question from each unit.
 4. Each question carries 10 marks and may have a, b, c, d as sub questions.

Part-A

All the following questions carry equal marks

(10x1M=10 Marks)

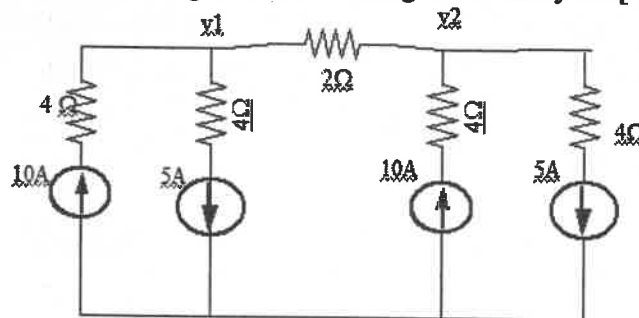
1. a. State Norton's theorem.
b. Write the expression for equivalent resistance for 'n' number of resistors in parallel connection.
c. List the merits of three phase circuit over single phase circuit.
d. State the principle of operation of a transformer.
e. Why the transformer rating is in kVA and not in kW?
f. List out the purpose of commutator and brushes.
g. Define the Zener diode.
h. What is the diffusion.
i. What is the FET.
j. Define the depletion MOSFET.

Part-B

Answer All the following questions.

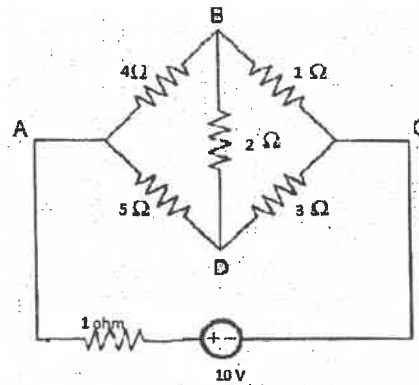
(10M X 5=50Marks)

- 2 Find the nodal voltages V_1 , V_2 for the given circuit using nodal analysis. [10M]



OR

- 3 In the circuit shown, determine the current through the 2 ohm resistor and the total current delivered by the battery. Use Kirchhoff's laws. [10M]



4 With a neat diagram, explain the principle operation of DC motor. [10M]

OR

5 Explain the various types of self-excited DC generator with diagrams. [10M]

6 Explain the open circuit test and short circuit test on a single-phase transformer. [10M]

OR

7 Explain the principle of operation of a transformer with a neat diagram. Also state where it is used in power systems. [10M]

8 Explain the PN junction diode and draw the V-I characteristics of diode. [10M]

OR

9 Explain the Half wave rectifier with neat diagram. [10M]

10 Explain the types of FET. [10M]

OR

11 Explain the enhancement MOSFET and draw the transfer characteristic. [10M]